Unit: mm

TOSHIBA Field-Effect Transistor Silicon N / P Channel MOS Type

SSM6L35FE

- High-Speed Switching Applications
- Analog Switch Applications

N-ch: 1.2-V drive
 P-ch: 1.2-V drive
 N-ch, P-ch, 2-in-1

• Low ON-resistance Q1 N-ch: R_{on} = 20 Ω (max) (@V_{GS} = 1.2 V)

: $R_{on} = 8 \Omega \text{ (max) (@V_{GS} = 1.5 V)}$: $R_{on} = 4 \Omega \text{ (max) (@V_{GS} = 2.5 V)}$

: $R_{on} = 3 \Omega \text{ (max) } (@V_{GS} = 4.0 \text{ V})$

Q2 P-ch: R_{on} = 44 Ω (max) (@V_{GS} = -1.2 V)

: R_{OI} = 22 Ω (max) (@V_{GS} = -1.5 V) : R_{OI} = 11 Ω (max) (@V_{GS} = -2.5 V)

: B = 90 (max) (@)/cc = 40.\/)

: $R_{on} = 8 \Omega \text{ (max) } (@V_{GS} = -4.0 \text{ V})$

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	20	V	
Gate-source voltage		V _{GSS}	±10	V	
Drain current	DC	ID	180	mA	
	Pulse	I _{DP}	360	IIIA	

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-20	V
Gate-source voltage		V_{GSS}	±10	٧
Drain current	DC	I _D	-100	mA
	Pulse	I _{DP}	-200	IIIA

Absolute Maximum Ratings (Ta = 25 °C) (Common to the Q1, Q2)

Characteristic	Symbol	Rating	Unit
Drain power dissipation	P _D (Note 1)	150	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

Mounted on an FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{ Cu Pad: } 0.135 \text{ mm}^2 \times 6)$

	1.6±0.05	***
1.0±0.05 1.0±0.05 1.0±0.05 1.0±0.55		6 5 4 0.05
0.55±0.05		0.12±0.05
	1.Source1	4.Source2
ES6	2.Gate1 3.Drain2	5.Gate2 6.Drain1
JEDEC	-	
JEITA	-	

2-2N1D

Weight: 3.0 mg (typ.)

TOSHIBA

Q1 Electrical Characteristics (Ta = 25°C)

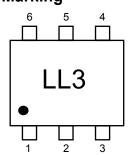
Charae	cteristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±10	μΑ
Drain-source brea	ıkdown voltage	V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0V$		20	_	_	V
Drain cutoff curren	ıt	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0V		_	_	1	μА
Gate threshold vol	tage	V_{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$		0.4	_	1.0	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 \text{ V}, I_{D} = 50 \text{ mA}$	(Note 2)	115	_	_	mS
Drain-source ON-resistance			$I_D = 50$ mA, $V_{GS} = 4$ V	(Note 2)	_	1.5	3	Ω
		R _{DS} (ON)	$I_D = 50 \text{ mA}, V_{GS} = 2.5 \text{ V}$	(Note 2)	_	2	4	
			I _D = 5 mA, V _{GS} = 1.5 V	(Note 2)	_	3	8	
			I _D = 5 mA, V _{GS} = 1.2 V	(Note 2)	_	5	20	
Input capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0V, f = 1 MHz		_	9.5	_	pF
Reverse transfer capacitance		C _{rss}			_	4.1	_	
Output capacitance		Coss			_	9.5	_	
Switching time	Turn-on time	t _{on}	V _{DD} = 3 V, I _D = 50 mA, V _{GS} = 0 to 2.5 V		_	115	_	
	Turn-off time	t _{off}			_	300	_	ns
Drain-source forward voltage		V _{DSF}	I _D = - 180 mA, V _{GS} = 0V	(Note 2)	_	-0.9	-1.2	V

Q2 Electrical Characteristics (Ta = 25°C)

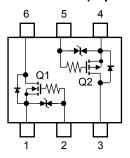
Charac	teristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±10	μА
Drain-source brea	kdown voltage	V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0 \text{ V}$		-20	_	_	V
Drain cutoff curren	t	I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V		_	_	-1	μА
Gate threshold voltage		V _{th}	$V_{DS} = -3 \text{ V}, I_{D} = -1 \text{ mA}$		-0.4	_	-1.0	V
Forward transfer admittance		Y _{fs}	$V_{DS} = -3 \text{ V}, I_{D} = -50 \text{ mA}$	(Note 2)	77	_	_	mS
Drain-source ON-resistance		R _{DS} (ON)	$I_D = -50 \text{ mA}, V_{GS} = -4 \text{ V}$	(Note 2)	_	4.3	8	Ω
			$I_D = -50 \text{ mA}, V_{GS} = -2.5 \text{ V}$	(Note 2)	_	5.6	11	
			I _D = -5 mA, V _{GS} = -1.5 V	(Note 2)	_	8.2	22	
			I _D = -2 mA, V _{GS} = -1.2 V	(Note 2)	_	11	44	
Input capacitance		C _{iss}	V _{DS} = -3 V, V _{GS} = 0 V, f = 1 MHz		_	12.2	_	pF
Reverse transfer capacitance		C _{rss}			_	6.5	_	
Output capacitance		Coss		_	10.4	_		
Switching time	Turn-on time	t _{on}	$V_{DD} = -3 \text{ V}, I_{D} = -50 \text{ mA}, V_{GS} = 0 \text{ to } -2.5 \text{ V}$		_	175	_	
	Turn-off time	t _{off}			_	251	_	ns
Drain-source forward voltage		V _{DSF}	I _D = 100 mA, V _{GS} = 0 V	(Note 2)	_	0.83	1.2	V

Note 2: Pulse test

Marking

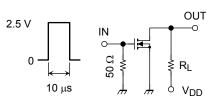


Equivalent Circuit (top view)



Q1 Switching Time Test Circuit

(a) Test Circuit



V_{DD} = 3 V D.U. ≤ 1%

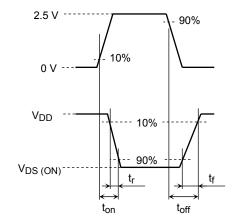
 V_{IN} : t_r , $t_f < 5$ ns $(Z_{out} = 50 \Omega)$

Common Source

 $Ta = 25^{\circ}C$

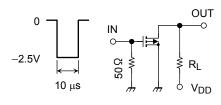


(c) Vout



Q2 Switching Time Test Circuit

(a) Test Circuit



 $V_{DD} = -3 V$ D.U. $\leq 1\%$

 V_{IN} : t_r , $t_f < 5$ ns

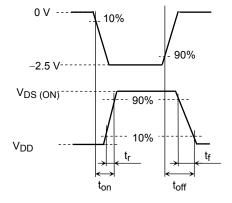
 $(Z_{Out} = 50 \Omega)$

Common Source

Ta = 25°C

(b) V_{IN}

(c) V_{OUT}



Q1 Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the Q1 of the SSM6L35FE). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

Q2 Usage Considerations

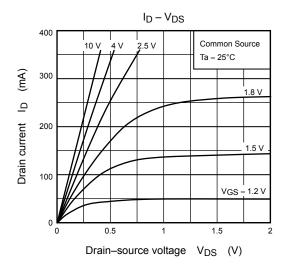
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (–1 mA for the Q2 of the SSM6L35FE). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

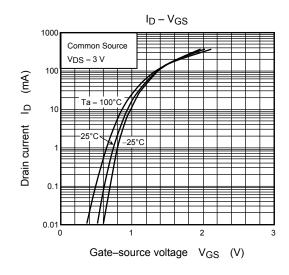
Take this into consideration when using the device.

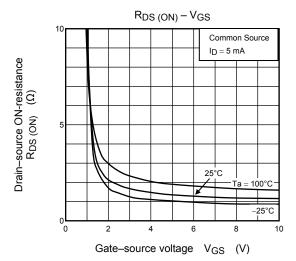
Handling Precaution

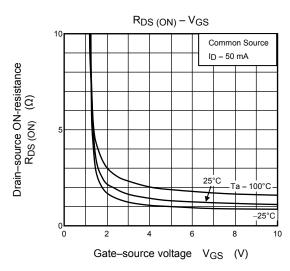
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

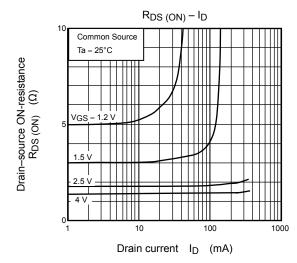
Q1 (N-ch MOSFET)

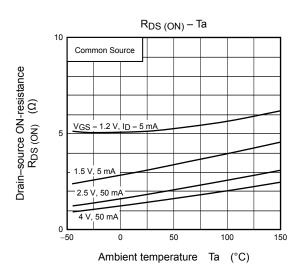




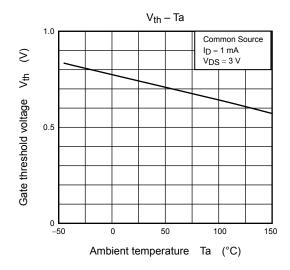


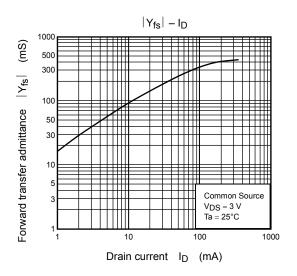


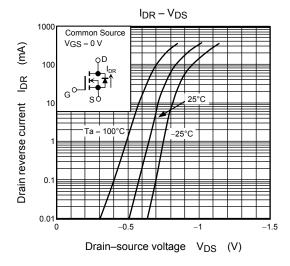


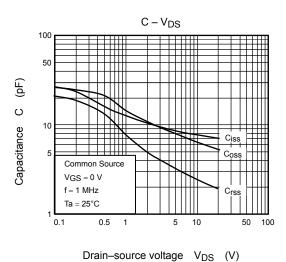


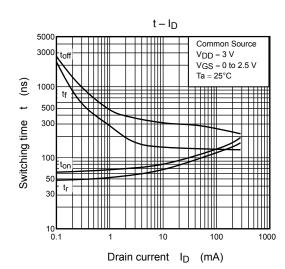
Q1 (N-ch MOSFET)



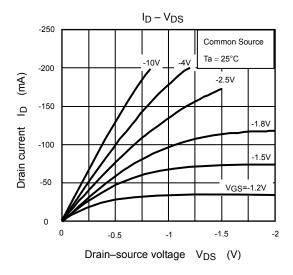


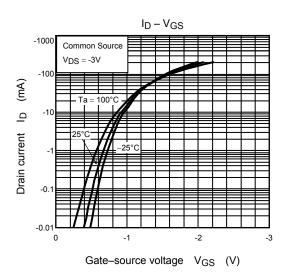


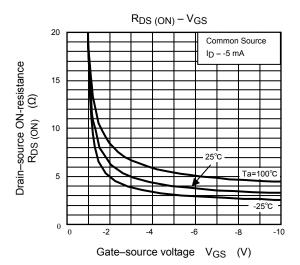


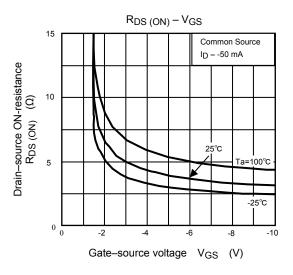


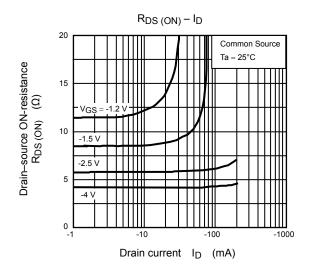
Q2 (P-ch MOSFET)

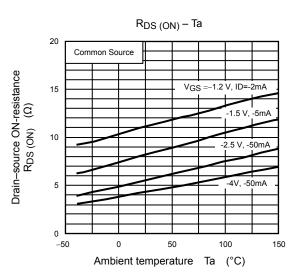




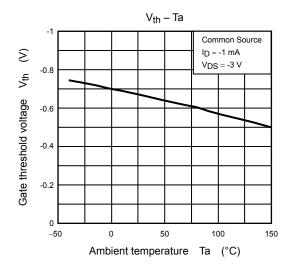


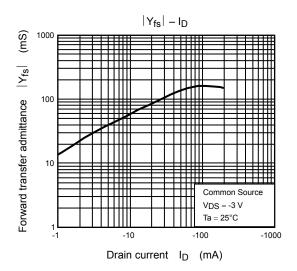


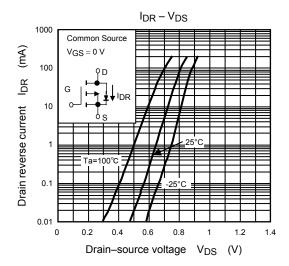


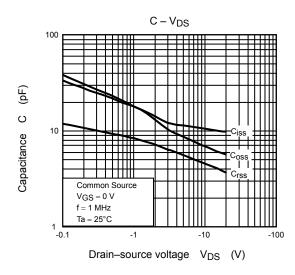


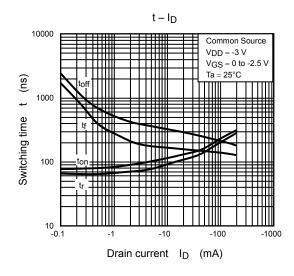
Q2 (P-ch MOSFET)

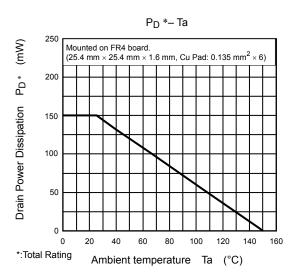












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